PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Shane Ching-Feng Hu

Attorney Docket No.: 501147.03 (30119/US/3)

Filed

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: Concurrently Herewith

Title

: STATIC CONTENT ADDRESSABLE MEMORY CELL

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with 37 C.F.R. §§ 1.56 and 1.97 through 1.98, applicant wishes to make known to the Patent and Trademark Office the references set forth on the attached form PTO-1449. This application relies, under 35 U.S.C. § 120, on the earlier filing date of prior Application No. 10/094,574, filed March 8, 2002. The references listed on the attached Form PTO-1449 were submitted to and/or cited by the Patent and Trademark Office in this prior application and, therefore, are not required to be provided in this application. If the Examiner wishes, copies will be provided upon request. Although the aforesaid references are made known to the Patent and Trademark Office in compliance with applicant's duty to disclose all information he is aware of which is believed relevant to the examination of the above-identified application, applicant believes that his invention is patentable.

Please acknowledge receipt of this Information Disclosure Statement and kindly make the cited references of record in the above-identified application.

Respectfully submitted,

DORSEY & WHITNEY LLP

Kimton N. Eng Registration No. 43,605

KNE:ajs

Enclosures:

Postcard

Form PTO-1449

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(REV.7-80)									

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO. 501147.03 (30119/US/3)

APPLICATION NO.

Not Yet Assigned

INFORMATION DISCLOSURE STATEMENT

(Use several sheets if necessary)

Shane Ching-Feng Hu

FILING DATE

APPLICANT(S)

GROUP ART UNIT

	Concurrently herewith Not Yet Assigned												
U.S. PATENT DOCUMENTS													
*EXAMINER		DOCUMENT NUMBER	DATE		NAME		CLASS	SUBCLASS	l	DATE			
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	OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)												
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* EXAMINER: Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in													
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